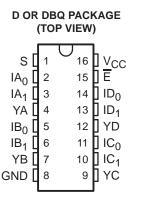
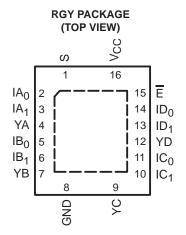
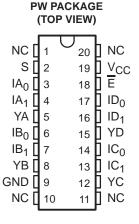
- Wide Bandwidth (BW = 300 MHz Min)
- Low Differential Crosstalk (X_{TALK} = -60 dB Typ)
- Low Power Consumption (I_{CC} = 3 μA Max)
- Bidirectional Data Flow, With Near-Zero Propagation Delay
- Low ON-State Resistance (r_{on} = 3 Ω Typ)
- V_{CC} Operating Range From 6 V to 6.5 V
- I_{off} Supports Partial-Power-Down Mode Operation

- Data and Control Inputs Provide Undershoot Clamp Diode
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Performance Tested Per JESD 22
 - 2000-V Human-Body Model (A114-B, Class II)
 - 1000-V Charged-Device Model (C101)
- Suitable for Both 10 Base-T/100 Base-T Signaling







NC - No internal connection

description/ordering information

The TI TS5L100 LAN switch is a 4-bit 1-of-2 multiplexer/demultiplexer with a single switch-enable (\overline{E}) input. When \overline{E} is low, the switch is enabled and the I port is connected to the Y port. When \overline{E} is high, the switch is disabled and the high-impedance state exists between the I and Y ports. The select (S) input controls the data path of the multiplexer/demultiplexer.

ORDERING INFORMATION

TA	PACKAG	et†	ORDERABLE PART NUMBER	TOP-SIDE MARKING		
	QFN – RGY	Tape and reel	TS5L100RGYR	TG100		
	0010 B	Tube TS5L100D				
200 1- 7000	SOIC - D	Tape and reel	TS5L100DR	TS5L100		
0°C to 70°C	SSOP (QSOP) – DBQ	Tape and reel	TS5L100DBQR	TG100		
	TSSOP – PW	Tube	TS5L100PW	TC400		
	1350P - PW	Tape and reel	TS5L100PWR	TG100		

[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



TS5L100 QUAD SPDT WIDE-BANDWIDTH LAN SWITCH WITH LOW ON-STATE RESISTANCE

SCDS163A - MAY 2004 - REVISED MAY 2004

description/ordering information (continued)

This device can be used to replace mechanical relays in LAN applications. This device has low r_{on} , wide bandwidth, and low differential crosstalk, making it suitable for 10 Base-T, 100 Base-T, and various other LAN applications.

This device is fully specified for partial-power-down applications using I_{off} . The I_{off} feature ensures that damaging current will not backflow through the device when it is powered down. The device has isolation during power off.

To ensure the high-impedance state during power up or power down, \overline{E} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

FUNCTION TABLE

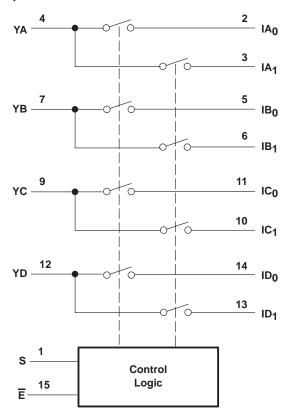
INP	JTS	INPUT/OUTPUT	FUNCTION
Ē	S	YX	FUNCTION
L	L	IX ₀	$YX = IX_0$
L	Н	IX ₁	$YX = IX_1$
Н	X	Z	Disconnect

PIN DESCRIPTIONS

PIN NAME	DESCRIPTION
IAn–IDn	Data I/Os
S	Select input
Ē	Enable input
YA-YD	Data I/Os



logic diagram (positive logic)





TS5L100 QUAD SPDT WIDE-BANDWIDTH LAN SWITCH WITH LOW ON-STATE RESISTANCE

SCDS163A - MAY 2004 - REVISED MAY 2004

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}	0.5 V to 7 V
Control input voltage range, V _{IN} (see Notes 1 and 2)	
Switch I/O voltage range, V _{I/O} (see Notes 1, 2, and 3)	0.5 V to 7 V
Control input clamp current, I _{IK} (V _{IN} < 0)	–50 mA
I/O port clamp current, I _{I/OK} (V _{I/O} < 0)	–50 mA
ON-state switch current, I _{I/O} (see Note 4)	±128 mA
Continuous current through V _{CC} or GND terminals	±100 mA
Package thermal impedance, θ _{JA} (see Note 5): D package	73°C/W
(see Note 5): DBQ package	90°C/W
(see Note 5): PW package	83°C/W
(see Note 6): RGY package	39°C/W
Storage temperature range, T _{stq}	-65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. All voltages are with respect to ground, unless otherwise specified.
 - 2. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
 - 3. V_I and V_O are used to denote specific conditions for V_{I/O}.
 - 4. II and IO are used to denote specific conditions for II/O.
 - 5. The package thermal impedance is calculated in accordance with JESD 51-7.
 - 6. The package thermal impedance is calculated in accordance with JESD 51-5.

recommended operating conditions (see Note 7)

		MIN	MAX	UNIT
VCC	Supply voltage	6	6.5	V
VIH	High-level control input voltage (\overline{E}, S)	2.5	6.5	V
V _{IL}	Low-level control input voltage (E, S)	0	0.8	V
TA	Operating free-air temperature	0	70	°C

NOTE 7: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



electrical characteristics over recommended operating free-air temperature range, $V_{CC} = 6 \text{ V}$ to 6.5 V (unless otherwise noted)

PARA	METER		TEST CONI	DITIONS	MIN	TYP [†]	MAX	UNIT
VIK	Ē, S	V _C C = 6 V,	$I_{IN} = -18 \text{ mA}$				-1.8	V
V _{hys}	Ē, S					150		mV
Vo		V _I = 4.5 V,	$\overline{E} = low,$	$R_L = 100 \Omega$, see Figure 11	3.7	4.06		V
lн	Ē, S	V _{CC} = 6.5 V,	VIN = VCC				±1	μΑ
Iμ	Ē, S	$V_{CC} = 6.5 V,$	V _{IN} = GND				±1	μΑ
l _{OZ} ‡		V _{CC} = 6.5 V,	$V_O = 0 \text{ to } 6.5 \text{ V},$ $V_I = 0,$	Switch OFF			±1	μΑ
I _{OS} §		V _{CC} = 6.5 V,	$V_O = 0 \text{ to } 0.5 \text{ V}_{CC},$ $V_I = 0,$	Switch ON	50			mA
l _{off}		$V_{CC} = 0$,	$V_0 = 0 \text{ to } 6.5 \text{ V},$	V _I = 0			1	μΑ
Icc		$V_{CC} = 6.5 V,$	$I_{I/O} = 0$,	Switch ON or OFF			3	μΑ
ΔlCC	Ē, S	$V_{CC} = 6.5 V,$	One input at 3.4 V,	Other inputs at V _{CC} or GND			6	mA
ICCD		V _{CC} = 6.5 V,	I and Y ports open,	V _{IN} input switching 50% duty cycle			0.35	mA/ MHz
C _{IN}	Ē, S	f = 1 MHz				3.5		рF
0	I port	1,, 0	f = 1 MHz,	Cuitab OFF		4.5		
COFF	Y port	$V_{I} = 0,$	Outputs open,	Switch OFF		6.5		pF
CON		V _I = 0,	f = 1 MHz, Outputs open,	Switch ON		14		pF
	M1	.,	0 11 1 011		7.5	11.2	19	
r _{on}	M2	$V_{ } = 4.5 \text{ V},$	Switch ON,	Switch ON, $R_L = 100 \Omega$, see Figure 11		3	6	Ω
Δr_{on}		V _I = 4.5 V,	Switch ON			1	2	Ω

 $V_I,\,V_O,\,I_I,\,$ and I_O refer to I/O pins. V_{IN} refers to the control inputs.

switching characteristics over recommended operating free-air temperature range, V_{CC} = 6 V to 6.5 V, R_L = 100 Ω , C_L = 35 pF (unless otherwise noted) (see Figure 7)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	MIN MAX	UNIT
ton	S	Υ	7	ns
^t OFF	S	Υ	4	ns

[†] All typical values are at V_{CC} = 6.2 V (unless otherwise noted), T_A = 25°C.

dynamic characteristics over recommended operating free-air temperature range, V_{CC} = 6 V to 6.5 V (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
X _{TALK} (Diff)	R_L = 100 Ω, f = 10 MHz, see Figure 12, t_f = t_f = 2 ns	-40	-60		dB
XTALK	R_L = 100 Ω, f = 30 MHz, see Figure 9		-50		dB
O _{IRR}	R_L = 100 Ω, f = 30 MHz, see Figure 10		-40		dB
BW	R_L = 100 Ω, see Figure 8		350		MHz

[†] All typical values are at V_{CC} = 6.2 V (unless otherwise noted), T_A = 25°C.



[†] All typical values are at V_{CC} = 6.2 V (unless otherwise noted), T_A = 25°C.

[‡] For I/O ports, I_{OZ} includes the input leakage current.

[§] The IOS test is applicable to only one ON channel at a time. The duration of this test is less than one second.

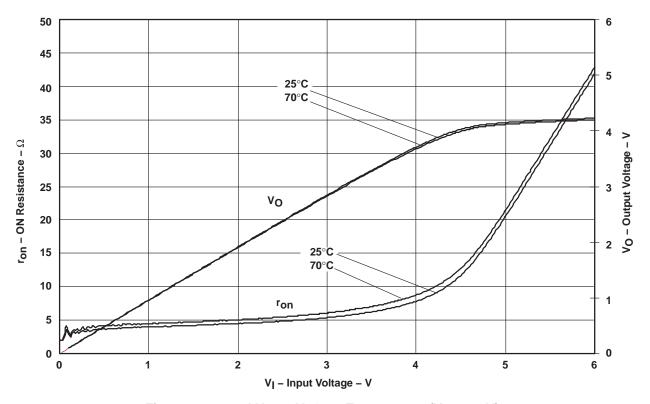


Figure 1. r_{on} and V_O vs V_I Over Temperature (V_{CC} = 6 V)



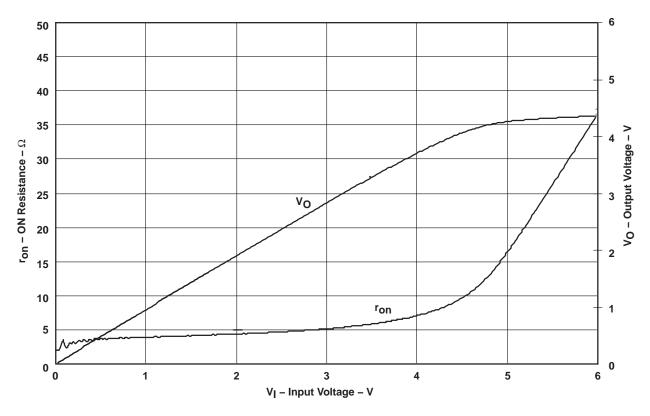
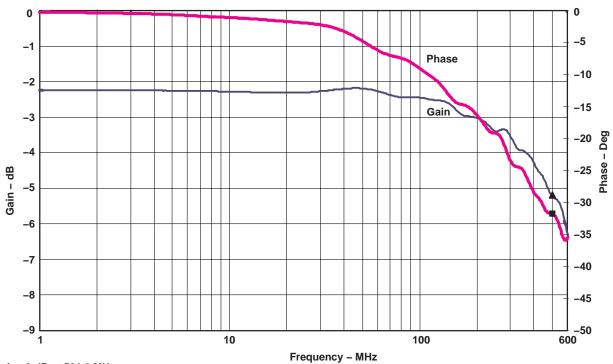


Figure 2. r_{on} and V_{O} vs V_{I} (V_{CC} = 6.2 V and T_{A} = 25°C)

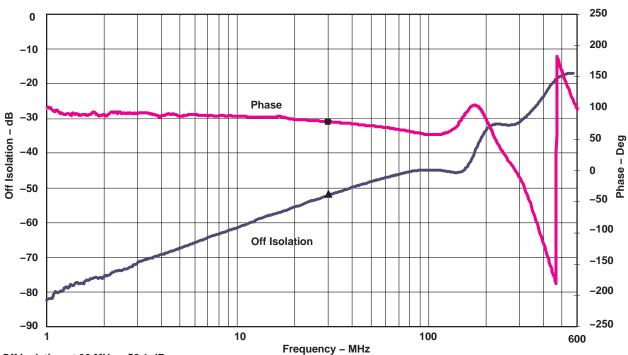




- ▲ Gain -3 dB at 501.2 MHz
- Phase at -3-dB Frequency, -31.7 Degrees

Figure 3. Gain/Phase vs Frequency





- ▲ Off Isolation at 30 MHz, -52.1 dB
- Phase at 30 MHz, 77 Degrees

Figure 4. Off Isolation vs Frequency



- ▲ Crosstalk at 30 MHz, -54 dB
- Phase at 30 MHz, 93.2 Degrees

Figure 5. Crosstalk vs Frequency



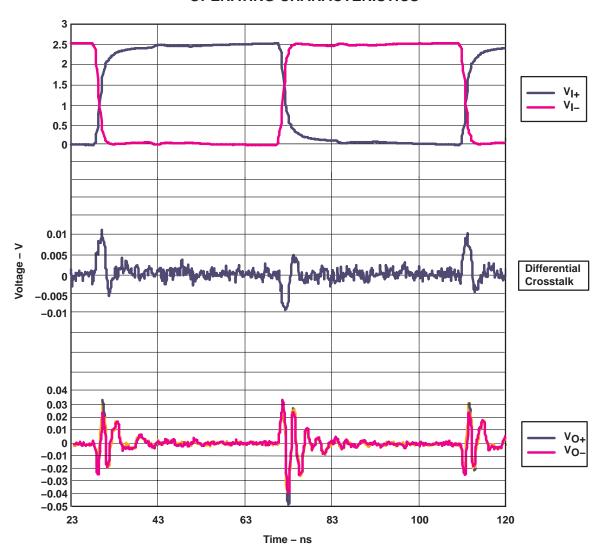
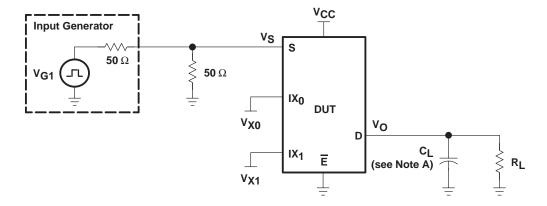


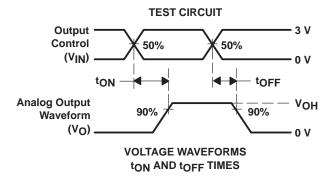
Figure 6. Differential Crosstalk



PARAMETER MEASUREMENT INFORMATION



TEST	VCC	RL	CL	V _{X0}	V _{X1}
ton	6.2 V	100 Ω	35 pF	GND	4.5 V
	6.2 V	100 Ω	35 pF	4.5 V	GND
tOFF	6.2 V	100 Ω	35 pF	GND	4.5 V
	6.2 V	100 Ω	35 pF	4.5 V	GND



NOTES: A. C_L includes probe and jig capacitance.

- B. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $t_f \leq$ 2.5 ns, $t_f \leq$ 2.5 ns.
- C. The outputs are measured one at a time, with one transition per measurement.

Figure 7. Test Circuit and Voltage Waveforms

PARAMETER MEASUREMENT INFORMATION

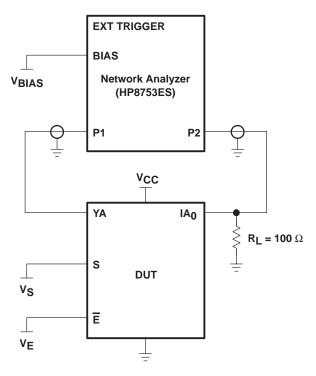


Figure 8. Test Circuit for Frequency Response (BW)

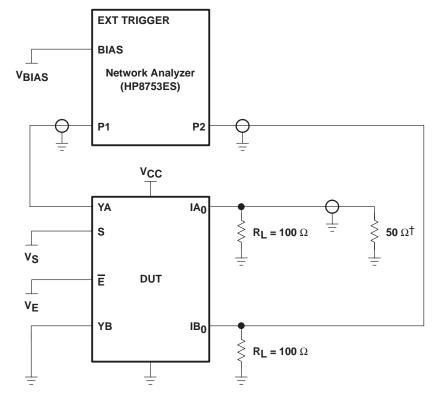
Frequency response is measured at the output of the ON channel. For example, when $V_S = 0$, $V_E = 0$, and YA is the input, the output is measured at IA₀. All unused analog I/O ports are left open.

HP8753ES setup

Average = 4 RBW = 3 kHz $V_{BIAS} = 0.35 V$ ST = 2 s P1 = 0 dBM



PARAMETER MEASUREMENT INFORMATION



 † A 50- $\!\Omega$ termination resistor is needed for the network analyzer.

Figure 9. Test Circuit for Crosstalk (X_{TALK})

Crosstalk is measured at the output of the nonadjacent ON channel. For example, when $V_S = 0$, $V_E = 0$, and YA is the input, the output is measured at IB₀. All unused analog input (Y) ports are connected to GND, and output (A) ports are connected to GND through 50- Ω pulldown resistors.

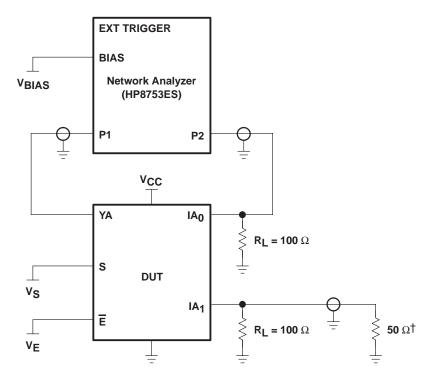
HP8753ES setup

Average = 4 RBW = 3 kHz $V_{BIAS} = 0.35 V$ ST = 2 s

P1 = 0 dBM



PARAMETER MEASUREMENT INFORMATION



 $^{^{\}dagger}$ A 50- $\!\Omega$ termination resistor is needed for the network analyzer.

Figure 10. Test Circuit for Off Isolation (OIRR)

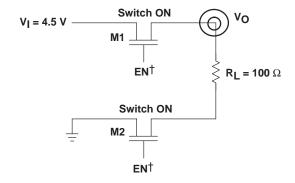
Off isolation is measured at the output of the OFF channel. For example, when $V_S = V_{CC}$, $V_E = 0$, and YA is the input, the output is measured at IA₀. All unused analog input (Y) ports are left open, and output (A) ports are connected to GND through $50-\Omega$ pulldown resistors.

HP8753ES setup

Average = 4 RBW = 3 kHz $V_{BIAS} = 0.35 V$ ST = 2 s P1 = 0 dBM



PARAMETER MEASUREMENT INFORMATION



†EN is the internal enable signal applied to the switch.

NOTE A: r_{ON} (M1) and r_{ON} (M2) are calculated from the voltage drop and current across the two terminals of M1 and M2, respectively.

Figure 11. Test Circuit for V_O and r_{on}

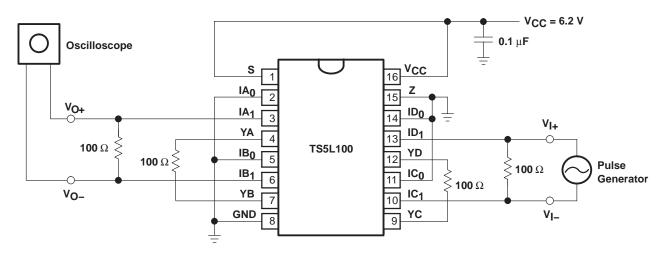


Figure 12. Differential Crosstalk Measurement

Differential crosstalk is a measure of coupling noise between a transmit and receive pair in the LAN application. Differential crosstalk depends on the edge rate, frequency, and load. This is calculated from the equation, $X_{TALK}(Diff)$ db = $20 \log V_O(Diff)/V_I(Diff)$, where $V_O(Diff)$ is the differential output voltage and $V_I(Diff)$ is the differential input voltage.

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PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
TS5L100D	ACTIVE	SOIC	D	16	40	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	TS5L100	Samples
TS5L100DBQR	ACTIVE	SSOP	DBQ	16	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	0 to 70	TG100	Samples
TS5L100DBQRG4	ACTIVE	SSOP	DBQ	16	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	0 to 70	TG100	Samples
TS5L100DG4	ACTIVE	SOIC	D	16	40	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	TS5L100	Samples
TS5L100DR	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	TS5L100	Samples
TS5L100PWR	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	TG100	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.



PACKAGE OPTION ADDENDUM

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TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

all differsions are norminal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TS5L100DBQR	SSOP	DBQ	16	2500	330.0	12.5	6.4	5.2	2.1	8.0	12.0	Q1
TS5L100DR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
TS5L100PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1

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*All dimensions are nominal

7 til difficiono di c momina							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TS5L100DBQR	SSOP	DBQ	16	2500	340.5	338.1	20.6
TS5L100DR	SOIC	D	16	2500	340.5	336.1	32.0
TS5L100PWR	TSSOP	PW	20	2000	853.0	449.0	35.0

PW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



PW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



- All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.





SHRINK SMALL-OUTLINE PACKAGE



- 1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 inch, per side.
- 4. This dimension does not include interlead flash.5. Reference JEDEC registration MO-137, variation AB.



SHRINK SMALL-OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SHRINK SMALL-OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



D (R-PDS0-G16)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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